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organic metal chalcogenides CuxBHT (BHT = benzenehexathiol; x = 3, 4, and 5.5)†

Facile synthesis, precise species control and

chemical transformation of highly conducting

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The design of conducting organic metal chalcogenides (OMCs) has attracted extensive attention for their applications in diverse areas. However, only a handful of OMCs exhibit appealing electrical transport properties due to the limited synthetic approaches. Herein, a facile and controllable synthetic approach for the preparation of highly crystalline benzenehexathiol (BHT)-based OMCs using Cu₂O as a precursor is reported. Under heterogeneous conditions, a series of highly conducting organic metal chalcogenides Cu_xBHT (x = 3, 4, and 5.5) were precisely constructed via variation of the molar ratio between Cu₂O and BHT. In particular, a fascinating chemical transformation phenomenon was discovered in this work. This is the first time that a phase transition has been observed in conducting OMCs, with the semiconducting species (Cu₄BHT and Cu_{5.5}BHT) being converted to metallic species (Cu₃BHT) under delicate oxidation regulation. This work provides a prominent paradigm for constructing highly crystalline OMCs, and opens up the possibility of developing OMCs with different structural topologies through chemical transformation.

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Introduction

Organic metal chalcogenides (OMCs) refer to a class of hybrid materials containing continuous M-X (X = S, Se, Te) networks and organic units covalently linked via chalcogen atoms.^{1,2} Owing to their highly tunable electronic structures and electrical transport properties, OMCs have received extensive attention in recent years.^{3,4} Based on their chemical and electronic structures, OMCs can be divided into two subclasses. The first type of OMCs has one-dimensional (1D) and two-dimensional (2D) organic units separated by inorganic cores, and there is weak electronic coupling between the inorganic and organic subunits. This species is the most reported one, which is usually constructed with ligands bearing only one chalcogen coordination group.⁵⁻⁷ Due to their 1D or 2D core-shell structures, highly anisotropic transport properties could be expected which leads to relatively inferior performance. This is especially evident for OMCs obtained as polycrystalline samples.8 This situation has changed obviously with the emergence of the 2nd generation OMCs constructed from benzenehexathiol (BHT), which display strong electronic coupling among the inorganic subunits as well as between the organic and inorganic subunits, while the organic units (conjugated molecular systems) are embedded in the inorganic networks. Apart from the commonly observed 2D honeycomb lattice containing discrete MS₄ subunits separated by benzene rings, 9,10 BHT displays great flexibility in constructing coordination polymers with different structural topologies. From the early reported Pb_3BHT^{11} to the later Ag_5BHT^{12} and Cu_xBHT (x = 3, 4, and 5.5), 13,14 all these materials are OMCs with 2D or complex 3D

Compared with the 1st generation OMCs, BHT-based 2nd generation OMCs display superior electrical transport properties, 15 as well as great potential for electrochemical catalysts, 10,16 transparent electrodes¹⁷ and energy storage devices. ^{18,19} Moreover, exotic quantum phenomena have been observed in Cu₃BHT such as unconventional superconductivity and quantum spin liquid (QSL) behaviour. 20,21 All these characteristics make these BHT-based OMCs extremely attractive especially the CuxBHT family. However, the synthetic methods that are crucial for crystallinity and phase purity control are less investigated. For Cu₄BHT and Cu_{5,5}BHT, it is supposed that unintentional oxidation of the ligand plays a critical role in the resulting species control according to their nonstoichiometric composition.¹³ But it remains a highly tricky process for the

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synthesis of Cu_{5.5}BHT with sufficient phase purity through a homogeneous reaction. In addition, the tendency of Cu_{5.5}BHT converting to Cu₄BHT and even to Cu₃BHT has been observed with the reaction prolonged. But how to achieve a controllable transformation among these CuxBHT members is still elusive. The solution to this conundrum will offer an alternative synthesis strategy for these OMCs and will provide valuable information about the chemical state of building units in the polymers.

Herein, we successfully obtained all members of the Cu_rBHT (x = 3, 4, and 5.5) family through a facile heterogeneous reaction using Cu₂O as the copper source. The identity and phase purity of the resulting OMCs can be easily controlled by modulating the molar ratio of Cu₂O and BHT. Furthermore, we discovered that the chemical transformation can be realized within the CuxBHT family by using tris(4-bromophenyl)aminium hexachloroantimonate ((4-BrPh)₃NSbCl₆) as the oxidizing reagent. Under precise oxidation regulation with (4-BrPh)₃NSbCl₆, Cu_{5.5}BHT can be converted to Cu₄BHT, and even to Cu₃BHT under further oxidation. This is the first time that such fascinating chemical transformation among the semiconducting OMCs (Cu_{5.5}BHT to Cu₄BHT), semiconducting to metallic OMCs (Cu_{5.5}BHT, Cu₄BHT to Cu₃BHT), has been observed. These results provide a simple and controllable strategy for the synthesis of highly crystalline OMCs, and highlight the significance of chemical structure regulation as well as the electronic structure modulation of OMCs by a chemical method.

Results and discussion

Synthesis and characterization

As schemed in Fig. 1, Cu_xBHT series were prepared at 80 °C by modulating appropriate stoichiometric ratios between Cu₂O

and BHT. Under an argon atmosphere, when 1.5 equivalents of Cu₂O (23.6 mg, 0.165 mmol) and BHT (30 mg, 0.11 mmol) were mixed in 30 mL of degassed ethanol and reacted for 72 h, a black Cu₃BHT sample was obtained. Similarly, when 2 equivalents of Cu₂O (31.5 mg, 0.22 mmol) and BHT (30 mg, 0.11 mmol) reacted for 48 h in 30 mL of degassed ethanol, a dark blue Cu₄BHT was obtained. When 2.75 equivalents of Cu₂O (43.3 mg, 0.303 mmol) and BHT (30 mg, 0.11 mmol) reacted for 48 h in 30 mL of degassed acetonitrile, a dark green $Cu_{5.5}BHT$ was obtained. The strong signal at $\sim 2490 \text{ cm}^{-1}$ that can be ascribed to the S-H stretching vibration in BHT disappeared (Fig. S1, ESI†), indicating that all the thiol groups of BHT participated in the reaction with Cu₂O. Besides, powder X-ray diffraction (PXRD), elemental analysis (EA), and inductively coupled plasma (ICP) were performed to confirm that the attained samples had the same components and structures as previously reported (Fig. S2-S4, see the ESI†). 13,20 The selfassembly coordination and reaction kinetics between Cu2O and thiolate species are quite unique.8,22,23 We have observed that Cu₃BHT can also be obtained by a long-term reaction of 1.5 equivalents of Cu₂O with BHT, which is quite different from the previously reported CuCl₂ (Fig. 1). 16 Recent magnetic susceptibility measurements²⁰ in Cu₃BHT unveiled that the oxidation state of Cu is +2, and thus we infer that the Cu+ source is oxidized to Cu2+ gradually during the reaction process.

Typically, PXRD data were collected to investigate the crystallinity of the obtained samples. As evidenced by sharp, wellisolated diffraction peaks, the crystallinity of Cu₃BHT is much higher than that of the products obtained with Cu²⁺ salts as reactants (Fig. S2, ESI†). Meanwhile, the morphologies of CuxBHT (x = 3, 4, and 5.5) were characterized by scanning electron microscopy (SEM) and transmission electron microscopy (TEM)

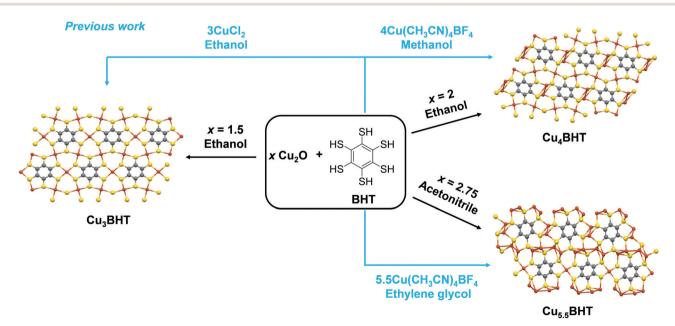


Fig. 1 Comparison of the synthetic methods of Cu_xBHT (x = 3, 4, and 5.5). The schematic synthesis of Cu_xBHT using different metal sources and reaction solvents. The previously reported pathways (ref. 13 and 16) are indicated by blue lines and text.

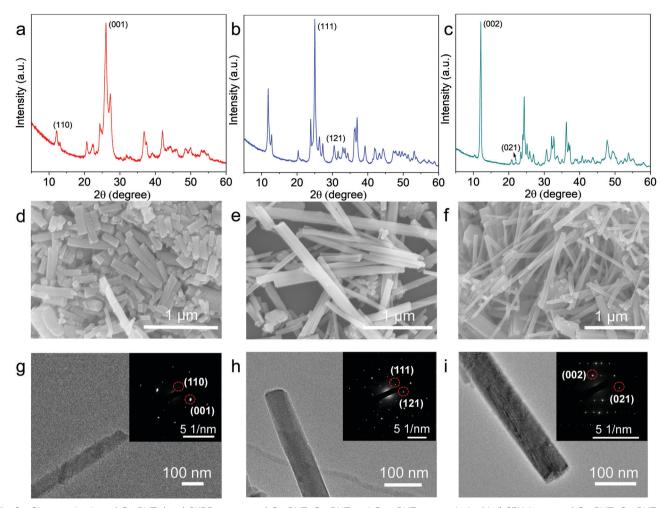


Fig. 2 Characterization of Cu_xBHT. (a-c) PXRD patterns of Cu₃BHT, Cu₄BHT and Cu_{5.5}BHT, respectively. (d-f) SEM images of Cu₃BHT, Cu₄BHT and Cu_{5.5}BHT, respectively. (g-i) TEM images of Cu₃BHT, Cu₄BHT and Cu_{5.5}BHT, respectively. Insets correspond to SAED patterns.

(Fig. 2). As indicated in the SEM images, all three samples displayed regular rod-like structures with a smooth surface and uniform size. The as-prepared nanorods are a few tens of nanometers in diameter and range from 500 nm (Cu₃BHT) to 2 µm (Cu₄BHT and Cu_{5.5}BHT) in length (Fig. 2d-f), which are longer than the nanocrystals prepared with Cu²⁺ and [Cu(CH₃CN)₄]BF₄ salts. 13,16 In particular, the selected area electron diffraction (SAED) pattern of an individual nanorod revealed regularly spaced arrays of diffraction spots, which can be assigned very well to the respective crystal indices, as shown in Fig. 2g-i. All the PXRD, SEM and SAED results verified that the samples prepared with Cu₂O as precursors are highly crystalline OMCs, which are expected to be applied in microelectronic devices based on nano-crystalline materials. The improved crystallinity can be attributed to three aspects. First, it is believed that temperature is a crucial parameter during the growth process of OMCs. Generally, higher temperatures will improve the crystallinity of the resulting materials as the coordination bonding is more reversible, and defects can be healed during the crystal growth process. Second, the slow nucleation and growth process are critically important to obtain highly crystalline OMCs. Compared to common Cu²⁺ sources, Cu(1) salts have a moderate reaction rate with organothiolates due to their more complicated d10 chemistry.24,25 Furthermore, BHT and Cu₂O have poor solubility in reaction solvents, which reduces the reaction concentration and diffusion rate of precursors, thus resulting in improved crystallinity.

Charge transport properties of CuxBHT

Electrical property characterization will provide further evidence on the identity of these Cu_rBHTs. To investigate the charge transport properties of these OMCs, the variable-temperature conductivities of the pressed pellets of Cu_xBHT were analysed using a standard four-probe method. As shown in Fig. 3, the conductivities of all the CuxBHT samples are compared with the previously reported results and are significantly higher than those of the most reported OMCs, 8,15,19,26 thus rendering them promising potential for applications in the microelectronics industry. 27,28 Among these three OMCs, Cu₃BHT features the highest electrical conductivity (215 to 286 S cm⁻¹ with an average value of 244 S cm⁻¹) compared with those of Cu₄BHT (153 to 184 S cm⁻¹ with an average value of 170 S cm⁻¹) and Cu_{5.5}BHT (144-166 S cm⁻¹ with an average value of 155 S cm⁻¹). According to

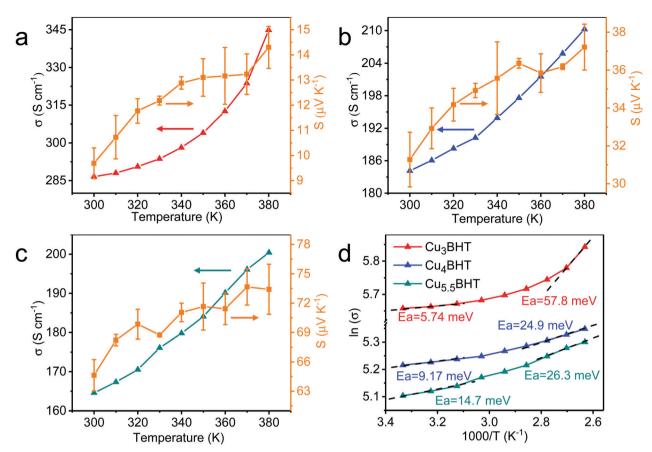


Fig. 3 The charge transport properties of Cu_xBHT. (a-c) Curves of the variable-temperature electrical conductivity and Seebeck coefficient of Cu₃BHT, Cu_4BHT and $Cu_{5.5}BHT$, respectively. (d) Plots of $\ln \sigma(T)$ versus 1000/T of Cu_xBHT .

Arrhenius fitting, the plots of $\ln \sigma(T)$ versus the reciprocal of the temperature give the activation energy (E_a) of each sample (Fig. 3d). The E_a values for the electron hopping of these three OMCs at 300 K are in the sequence of Cu₃BHT (5.74 meV) < Cu₄BHT (9.17 meV) < Cu_{5.5}BHT (14.7 meV), which explains the fact that the conductivities of CuxBHT members are in the sequence of $Cu_3BHT > Cu_4BHT > Cu_{5.5}BHT$. With the temperature increasing from 300 K to 380 K, the $E_{\rm a}$ of all three OMCs continuously increases, which indicates the defects, most likely the grain boundaries between neighbouring Cu_rBHT nanocrystals that influence the charge transport behaviour.

It is obvious that the E_a of three OMCs appears quite small, especially in low temperature ranges. To figure out the origin of low E_a and observed high conductivities, three samples were subjected to ultraviolet photoelectron spectroscopy (UPS).

As illustrated in Fig. 4, all three samples displayed a clear Fermi edge near the top of the valence band, indicating that they are metallic conductors or degenerate semiconductors. As disclosed by band structure calculations, three networks exhibit substantial differences in their electronic structures. Cu₃BHT has a metallic nature, ^{20,21} while Cu₄BHT and Cu_{5,5}BHT behave as degenerate semiconductors. 13 The differences in structural topology as well as the variation of hybridization between the d orbitals of the Cu ions and the π orbitals of the BHT ligands result in different band structures in the Cu_xBHT family.

In addition, the variable-temperature Seebeck coefficient measurement displays that Cu₃BHT has a small Seebeck coefficient ranging from 9 to 15 μV K⁻¹ (Fig. 3a-c). Such a low Seebeck coefficient and the weak temperature dependence of conductivity in Cu₃BHT are typically observed in metals or highly conducting polymers, ²⁹ which further demonstrates its metallic characteristic. In comparison, the Seebeck coefficients of Cu₄BHT and Cu₅ ₅BHT are 30-40 μ V K⁻¹ and 60-80 μ V K⁻¹, respectively, which are about 3~6 times larger than that of Cu₃BHT. The higher Seebeck coefficients suggest that Cu₄BHT and Cu₅5BHT are more like degenerate semiconductors rather than metals, which is consistent with band structure calculation results. 13

Oxidation regulation within the CuxBHT family

Enlightened by the knowledge that redox has a significant influence on the oxidation states of metal bis(dithiolene) species and their electrical transport properties, 12 here, valence-variable (4-BrPh)₃NSbCl₆ is employed as the oxidizing reagent since it is known to better control the oxidation states of the metal bis(dithiolene) unit. 15,30,31 In order to investigate the influence of the degree of oxidation on the final phases, different equivalents of (4-BrPh)₃NSbCl₆ were added to Cu₄BHT and Cu_{5.5}BHT using methanol as a reaction medium. After post-preparation modification, the crystallinity and composition of the oxidation products were identified by PXRD, EA and ICP measurements

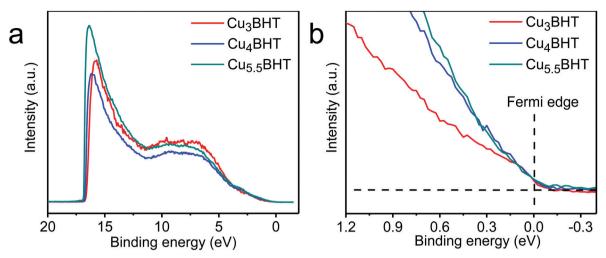


Fig. 4 The UPS analysis of Cu_xBHT acquired at 300 K. The full spectra and the Fermi edge are shown in (a) and (b), respectively

(see Fig. S5 and S6, ESI†). Surprisingly, under an argon atmosphere, when 1.5 equivalents of (4-BrPh)₃NSbCl₆ (29.4 mg, 0.036 mmol) were added to Cu_{5.5}BHT (15 mg, 0.024 mmol) in 25 mL of CH₃OH, a dark blue Cu₄BHT sample was obtained at room temperature. When 2.5 equivalents of (4-BrPh)₃NSbCl₆ (49 mg, 0.06 mmol) were added to Cu_{5.5}BHT (15 mg, 0.024 mmol) or 1 equivalent of (4-BrPh)₃NSbCl₆ (24 mg, 0.029 mmol) was added to Cu₄BHT (15 mg, 0.029 mmol), a black Cu₃BHT sample was obtained (Fig. 5 and Fig. S2, ESI†). Such oxidation regulation accompanied by the changes in topological structures is quite rare among the other coordination polymers ever reported. 32-35 In addition, with the deepening oxidation degree, the colours of polycrystalline samples become gradually darker, varying from dark green, dark blue to black (Fig. 5). The visible difference in colours suggested that Cu_rBHT series have potential as light-harvesting or electrochromic materials.

During oxidation, the Cu-BHT networks lose electrons and trigger structural conversions, and the entire system remains electrically neutral. After oxidation, the elemental composition of the oxidized products was analysed by X-ray photoelectron spectroscopy (XPS) (Fig. S7, ESI†). The Cu (2p) region exhibited a strong satellite peak, suggesting that the valence state of Cu in the remaining filtrate is +2. In the high-resolution Sb 3d XPS spectrum, two sets of peaks with binding energies of ~ 540.4 and \sim 531.1 eV were observed and assigned, respectively, to the $3d_{3/2}$ and $3d_{5/2}$ levels of Sb, revealing that $[SbCl_6]^-$ was reduced to [SbCl₆]³⁻. On the basis of the charge balance, when Cu_{5.5}BHT loses 3 electrons, Cu₄BHT was generated, while Cu₃BHT was obtained when it loses 5 electrons. Similarly, Cu₄BHT can

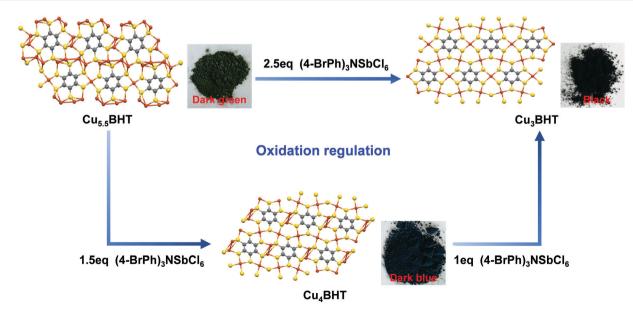


Fig. 5 Oxidation regulation within the Cu_xBHT family. Schematic illustration of phase transition in Cu_xBHT species upon delicate oxidation regulation with (4-BrPh)₃NSbCl₆. Photograph shows the colours of each Cu_xBHT species.

transform into Cu₃BHT after losing 2 electrons, so Cu₄BHT is more like an intermediate state of transition from Cu_{5.5}BHT to Cu₃BHT. But it is a controversial issue to give a clear definition of whether the oxidation process is metal-centred or ligand-centred. We can infer that the copper bis(dithiolene) coordination unit, as an indivisible moiety, acts as an electron reservoir that can undergo complex redox switching as a whole. Thus, the ligand and the metal here cooperate in a synergistic manner, and their interplay facilitates the redox switching process. Therefore, the uniqueness of the oxidation states of BHT and the flexibility of the coordination geometries of Cu(1) ions result in rich members in the Cu_xBHT family. Additionally, Cu_{5.5}BHT and Cu₄BHT can be regarded as the reaction precursors of Cu₃BHT employing valence-variable [SbCl₆] as an oxidant. With this in mind, we hypothesized that the structural transformation induced by oxidation could be a promising synthetic shortcut to prepare the desired OMCs. Since the structural transformations in the Cu_xBHT family are accompanied by the changes in the optical, electrical and magnetic properties, they are expected to be employed for advanced functional applications such as sensors or electrochromic devices.

Conclusions

In summary, three highly conducting OMCs - Cu₃BHT, Cu₄BHT and Cu_{5.5}BHT - have been effectively prepared and characterized. By modulating the suitable feed ratios between Cu2O and BHT, a series of Cu_xBHT (x = 3, 4, and 5.5) materials can be precisely generated, which has been evidenced by the combined analysis of EA, PXRD, SEM and SAED measurements. Here, the binary oxide Cu₂O as a metal source not only exhibits rich coordination capacity in constructing OMCs with different structural topologies, but also possesses moderate thiophilicity towards BHT, thereby obtaining a series of highly crystalline OMCs. It is particularly noteworthy that this synthetic pathway is facile and straightforward yet allows precise phase purity control. This discovery provides the possibility of producing new types of highly conducting OMCs. Most importantly, we demonstrate for the first time that the fantastic chemical transformation within the CuxBHT family can be realized under delicate oxidation regulation, in which both the semiconducting Cu_{5.5}BHT and Cu₄BHT can be converted to metallic Cu₃BHT. This interesting phenomenon highlights the importance of structural transformation for the control of electronic structures of OMCs. Considering the tailorable chemical structures and excellent performance of Cu_xBHT species, we believe that these OMCs have substantial potential for applications in the future.

Conflicts of interest

There are no conflicts to declare.

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Notes and references

- 1 W. P. Su, M. C. Hong, J. B. Weng, Y. C. Liang, Y. J. Zhao, R. Cao, Z. Y. Zhou and A. S. C. Chan, Inorg. Chim. Acta, 2002, **331**, 8–15.
- 2 H. Yan, J. N. Hohman, F. H. Li, C. Jia, D. Solis-Ibarra, B. Wu, J. E. P. Dahl, R. M. K. Carlson, B. A. Tkachenko, A. A. Fokin, P. R. Schreiner, A. Vailionis, T. R. Kim, T. P. Devereaux, Z.-X. Shen and N. A. Melosh, Nat. Mater., 2017, 16, 349-355.
- 3 O. Veselska and A. Demessence, Coord. Chem. Rev., 2018, 355, 240-270.
- 4 Y. Li, X. Jiang, Z. Fu, Q. Huang, G.-E. Wang, W.-H. Deng, C. Wang, Z. Li, W. Yin, B. Chen and G. Xu, Nat. Commun., 2020, 11, 261.
- 5 D. V. P. Massote and M. S. C. Mazzoni, Appl. Phys. Lett., 2016, 109, 133104.
- 6 Y. Zhang, T. Xia, K. M. Yu, F. Zhang, H. Yang, B. Liu, Y. An, Y. Yin and X. Chen, ChemPlusChem, 2014, 79, 559-563.
- 7 C. Lavenn, N. Guillou, M. Monge, D. Podbevsek, G. Ledoux, A. Fateeva and A. Demessence, Chem. Commun., 2016, 52, 9063-9066.
- 8 K. H. Low, V. A. Roy, S. S. Chui, S. L. Chan and C. M. Che, Chem. Commun., 2010, 46, 7328-7330.
- 9 T. Kambe, R. Sakamoto, K. Hoshiko, K. Takada, M. Miyachi, J. H. Ryu, S. Sasaki, J. Kim, K. Nakazato, M. Takata and H. Nishihara, J. Am. Chem. Soc., 2013, 135, 2462-2465.
- 10 A. J. Clough, J. W. Yoo, M. H. Mecklenburg and S. C. Marinescu, J. Am. Chem. Soc., 2015, 137, 118-121.
- 11 D. L. Turner, T. P. Vaid, P. W. Stephens, K. H. Stone, A. G. DiPasquale and A. L. Rheingold, J. Am. Chem. Soc., 2008, 130, 14-15.
- 12 X. Huang, H. Li, Z. Tu, L. Liu, X. Wu, J. Chen, Y. Liang, Y. Zou, Y. Yi, J. Sun, W. Xu and D. Zhu, J. Am. Chem. Soc., 2018, 140, 15153-15156.
- 13 X. Huang, Y. Qiu, Y. Wang, L. Liu, X. Wu, Y. Liang, Y. Cui, Y. Sun, Y. Zou, J. Zhu, W. Fang, J. Sun, W. Xu and D. Zhu, Angew. Chem., Int. Ed., 2020, 59, 22602-22609.
- 14 X. Huang, P. Sheng, Z. Tu, F. Zhang, J. Wang, H. Geng, Y. Zou, C. A. Di, Y. Yi, Y. Sun, W. Xu and D. Zhu, Nat. Commun., 2015, 6, 7408.
- 15 T. Kambe, R. Sakamoto, T. Kusamoto, T. Pal, N. Fukui, K. Hoshiko, T. Shimojima, Z. Wang, T. Hirahara, K. Ishizaka, S. Hasegawa, F. Liu and H. Nishihara, J. Am. Chem. Soc., 2014, 136, 14357-14360.
- 16 X. Huang, H. Yao, Y. Cui, W. Hao, J. Zhu, W. Xu and D. Zhu, ACS Appl. Mater. Interfaces, 2017, 9, 40752-40759.
- 17 Z. W. Jin, J. Yan, X. Huang, W. Xu, S. Y. Yang, D. B. Zhu and J. Z. Wang, Nano Energy, 2017, 40, 376-381.
- 18 Z. Wu, D. Adekoya, X. Huang, M. J. Kiefel, J. Xie, W. Xu, Q. Zhang, D. Zhu and S. Zhang, ACS Nano, 2020, 14, 12016-12026.

- 19 H. Banda, J. H. Dou, T. Chen, N. J. Libretto, M. Chaudhary, G. M. Bernard, J. T. Miller, V. K. Michaelis and M. Dinca, J. Am. Chem. Soc., 2021, 143, 2285-2292.
- 20 X. Huang, S. Zhang, L. Liu, L. Yu, G. Chen, W. Xu and D. Zhu, Angew. Chem., Int. Ed., 2018, 57, 146-150.
- 21 T. Takenaka, K. Ishihara, M. Roppongi, Y. Miao, Y. Mizukami, T. Makita, J. Tsurumi, S. Watanabe, J. Takeya, M. Yamashita, K. Torizuka, Y. Uwatoko, T. Sasaki, X. Huang, W. Xu, D. Zhu, N. Su, J. G. Cheng, T. Shibauchi and K. Hashimoto, Sci. Adv., 2021, 7, eabf3996.
- 22 N. Arisnabarreta, P. Paredes-Olivera, F. P. Cometto and E. M. Patrito, J. Phys. Chem. C, 2019, 123, 17283-17295.
- 23 L. Wu, Y. Jiao, K. Zhang, F. Wu, W. Zhao, M. Sun, A. Xie and W. Dong, J. Mater. Chem. C, 2019, 7, 11621-11631.
- 24 O. Veselska and A. Demessence, Coord. Chem. Rev., 2018, 355, 240-270.
- 25 O. Veselska, L. Cai, D. Podbevsek, G. Ledoux, N. Guillou, G. Pilet, A. Fateeva and A. Demessence, Inorg. Chem., 2018, 57, 2736-2743.
- 26 Y. Cui, J. Yan, Z. Chen, J. Zhang, Y. Zou, Y. Sun, W. Xu and D. Zhu, Adv. Sci., 2019, 6, 1802235.

- 27 K. T. Butler, C. H. Hendon and A. Walsh, ACS Appl. Mater. Interfaces, 2014, 6, 22044-22050.
- 28 E. A. Dolgopolova, A. J. Brandt, O. A. Ejegbavwo, A. S. Duke, T. D. Maddumapatabandi, R. P. Galhenage, B. W. Larson, O. G. Reid, S. C. Ammal, A. Heyden, M. Chandrashekhar, V. Stavila, D. A. Chen and N. B. Shustova, J. Am. Chem. Soc., 2017, 139, 5201-5209.
- 29 N. Massonnet, A. Carella, A. de Geyer, J. Faure-Vincent and J. P. Simonato, Chem. Sci., 2015, 6, 412-417.
- 30 J. F. Berry, F. A. Cotton, L. M. Daniels, C. A. Murillo and X. Wang, Inorg. Chem., 2003, 42, 2418-2427.
- 31 G. W. Cowell, A. Ledwith, A. C. White and H. J. Woods, J. Chem. Soc. B, 1970, 227-231.
- 32 J. J. Vittal, Coord. Chem. Rev., 2007, 251, 1781-1795.
- 33 G. K. Kole and J. J. Vittal, Chem. Soc. Rev., 2013, 42, 1755-1775.
- 34 T. H. Kim, Y. W. Shin, J. H. Jung, J. S. Kim and J. Kim, Angew. Chem., Int. Ed., 2008, 47, 685-688.
- 35 K. J. Lee, J. H. Lee, S. Jeoung and H. R. Moon, Acc. Chem. Res., 2017, 50, 2684-2692.